SURFACE MOUNT SILICON 3.0 AMP SCHOTTKY RECTIFIER



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMDFSHC3-100 is a 3.0 Amp silicon Schottky rectifier mounted in a durable epoxy surface mount case, utilizing glass passivated chips.

MARKING CODE: C3-100C



MAXIMUM RATINGS: (T_A=25°C unless otherwise noted)

	SYMBOL		UNITS	
Peak Repetitive Reverse Voltage	V_{RRM}	100	V	
DC Blocking Voltage	V_{R}	100	V	
Average Forward Current	IO	3.0	Α	
Peak Forward Surge Current (8.3ms)	I _{FSM}	100	Α	
Operating Junction Temperature	T_J	-55 to +125	°C	
Storage Temperature	T _{stg}	-55 to +150	°C	
Typical Thermal Resistance (Note 1)	$\Theta_{\sf JA}$	55	°C/W	
Typical Thermal Resistance (Note 1)	$\Theta_{\sf JL}$	17	°C/W	

SYMBOL	TEST CONDITIONS	TYP	MAX	UNITS
I_R	V _R =100V		500	μΑ
V_{F}	I _F =3.0A (Note 2)	0.78	0.85	V
Ст	V⊳=4.0V. f=1.0MHz	180		Pα

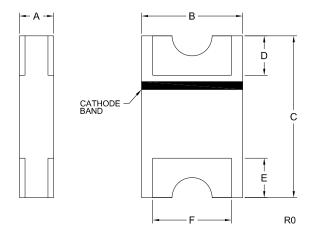
Notes: 1) FR-4 Epoxy PC Board with copper mounting pad area of 5.0mm^2

²⁾ Pulse test tp=300µs, Duty Cycle=1%





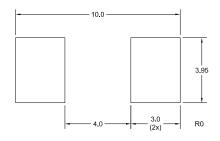
SMC DFN CASE - MECHANICAL OUTLINE



DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
Α	0.037	0.049	0.95	1.25		
В	0.193	0.201	4.90	5.10		
С	0.311	0.319	7.90	8.10		
D	0.073	0.081	1.85	2.05		
E	0.073	0.081	1.85	2.05		
F	0.154		3.90			

SMC DFN (REV: R0)

SUGGESTED MOUNTING PADS (Dimensions in mm)

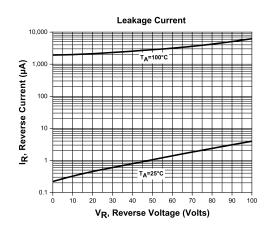


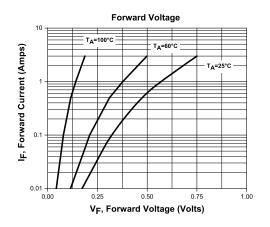
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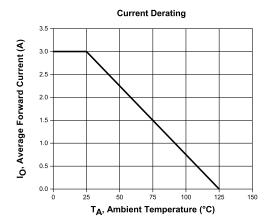


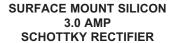


TYPICAL ELECTRICAL CHARACTERISTICS











TYPICAL APPLICATIONS

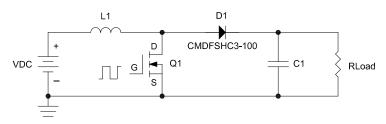


Figure 1. Boost Converter: One of the most traditional uses of the Schottky rectifier is in the boost converter, which requires a low-loss rectification element. The CMDFSH Series has been designed to highlight the main qualities of Schottky rectifiers in a space-efficient package; including a low forward voltage drop, fast turn-on time, and extremely fast recovery time. These attributes make the CMDFSH Series an excellent boost rectifier choice for any boost converter system.

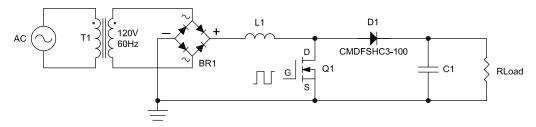


Figure 2. PFC Boost Converter: The most popular adaption of the boost converter is the power factor correction (PFC) boost converter. The power factor is the ratio of real power to actual power dissipated in a circuit. The actual power dissipation of a circuit is altered when inductive components are used in a design. This is due to the inductive reactance of the coil, which causes the current flowing through the system to lag behind the voltage in the system, causing the signals to fall out of phase. Power factor correction increases the power factor by using capacitance to create a leading current effect that compensates for the lagging current effect that is caused by the inductor.

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